

## **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>VS-6TQ035SPBF</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

## Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VS-6TQ035SPBF - DIODE SCHOTTKY 35V 6A D2PAK

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## VS-6TQ035SPbF, VS-6TQ040SPbF, VS-6TQ045SPbF

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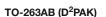
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COMPLIANT

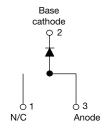
HALOGEN

FREE

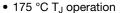
## **High Performance Schottky Rectifier, 6 A**

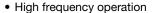


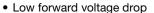


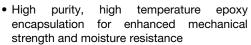


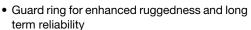
#### **FEATURES**

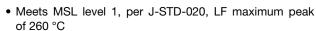














 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

PRODUCT SUMMARY						
Package TO-263AB (D <sup>2</sup> PAK)						
$I_{F(AV)}$	6 A					
$V_{R}$	35 V, 40 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.53 V					
I <sub>RM</sub>	7 mA at 125 °C					
$T_J$ max.	175 °C					
Diode variation	Single die					
E <sub>AS</sub>	8 mJ					

#### **DESCRIPTION**

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNI								
I <sub>F(AV)</sub>	Rectangular waveform	6	A					
V <sub>RRM</sub>	Range	35 to 45	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	690	A					
V <sub>F</sub>	6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.53	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-6TQ035SPbF	VS-6TQ040SPbF	VS-6TQ045SPbF	UNITS			
Maximum DC reverse voltage	$V_{R}$	35	40	45	V			
Maximum working peak reverse voltage	$V_{RWM}$	33	40	43	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 164 °C, rectangular waveform		6			
Maximum peak one cycle non-repetitive surge current	leo	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	690	Α		
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	140			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11.10 mH		8	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.20	А		

Revision: 08-Dec-14 1 Document Number: 94253



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## VS-6TQ035SPbF, VS-6TQ040SPbF, VS-6TQ045SPbF

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		6 A	T. <sub>1</sub> = 25 °C	0.60			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	12 A		0.73	v		
See fig. 1	VFM (')	6 A	T <sub>.I</sub> = 125 °C	0.53	V		
		12 A	1 J = 125 C	0.64			
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V D-4-4V	0.8	Л		
See fig. 2	IRM ('')	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7	mA		
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum		0.35	V		
Forward slope resistance	r <sub>t</sub>	ı ij = ij maximum	$T_J = T_J$ maximum		mΩ		
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal rang	400	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mi	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs			

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and stora temperature range	ge	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	2.2			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50 °C			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Manusting toward	minimum			6 (5)	kgf · cm		
Mounting torque maximum				12 (10)	(lbf · in)		
				6TQ03	35S		
Marking device	Marking device		Case style D <sup>2</sup> PAK	6TQ040S			
				6TQ045S			

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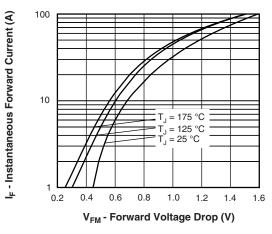


Fig. 1 - Maximum Forward Voltage Drop Characteristics

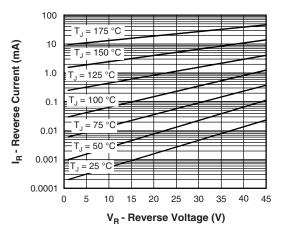


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

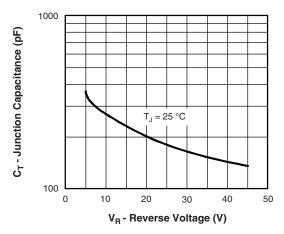


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

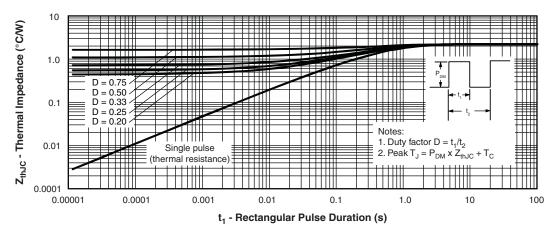


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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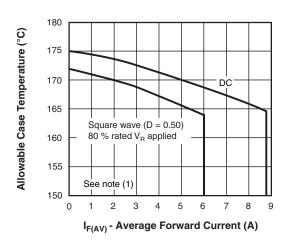


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

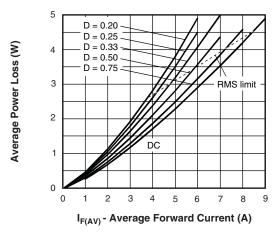


Fig. 6 - Forward Power Loss Characteristics

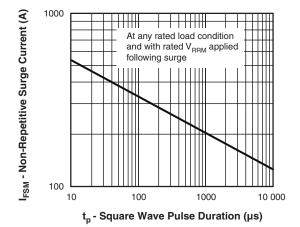


Fig. 7 - Maximum Non-Repetitive Surge Current

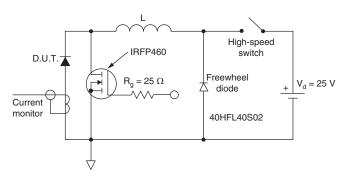


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse power loss = V_{R1} \times I_{R} (1 - D)$ ;  $I_{R}$  at  $V_{R1} = 80 \%$  rated  $V_{R}$ 

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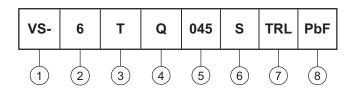
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#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

Current rating (6 A)

3 Package: T = TO-220

Schottky "Q" series 035 = 35 V

040 = 40 VVoltage ratings 045 = 45 V  $S = D^2PAK$ 

• None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 PbF = lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-6TQ035SPBF	50	1000	Antistatic plastic tubes					
VS-6TQ035STRRPBF	800	800	13" diameter plastic tape and reel					
VS-6TQ035STRLPBF	800	800	13" diameter plastic tape and reel					
VS-6TQ040SPBF	50	1000	Antistatic plastic tubes					
VS-6TQ040STRRPBF	800	800	13" diameter plastic tape and reel					
VS-6TQ040STRLPBF	800	800	13" diameter plastic tape and reel					
VS-6TQ045SPBF	50	1000	Antistatic plastic tubes					
VS-6TQ045STRRPBF	800	800	13" diameter plastic tape and reel					
VS-6TQ045STRLPBF	800	800	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95046			
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			

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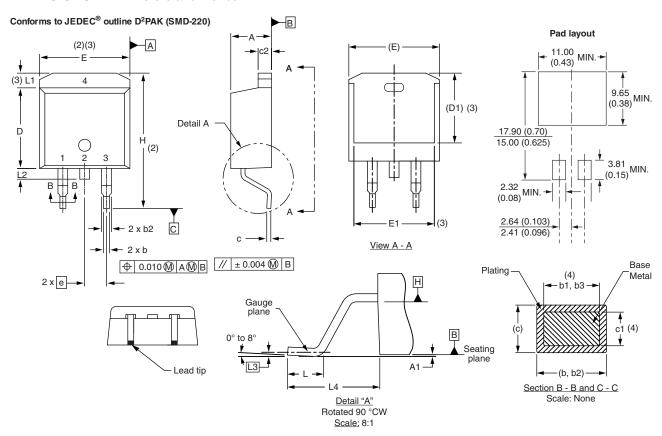


### **Outline Dimensions**

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## D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



	MILLIM	MILLIMETERS		INCHES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Δ.					
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1		1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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